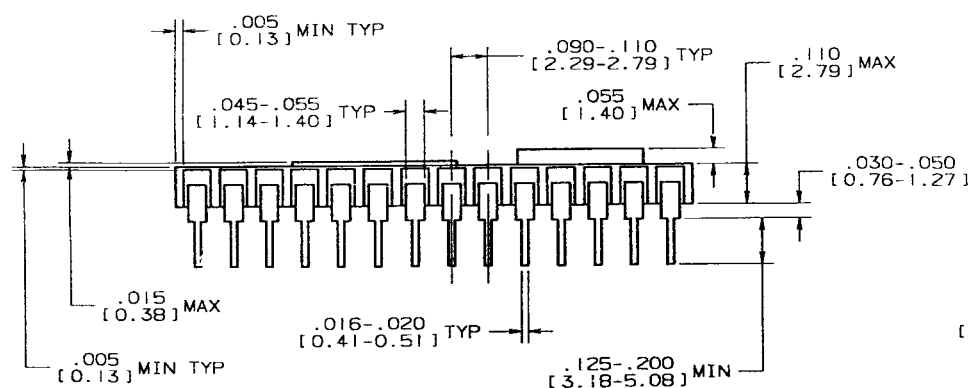
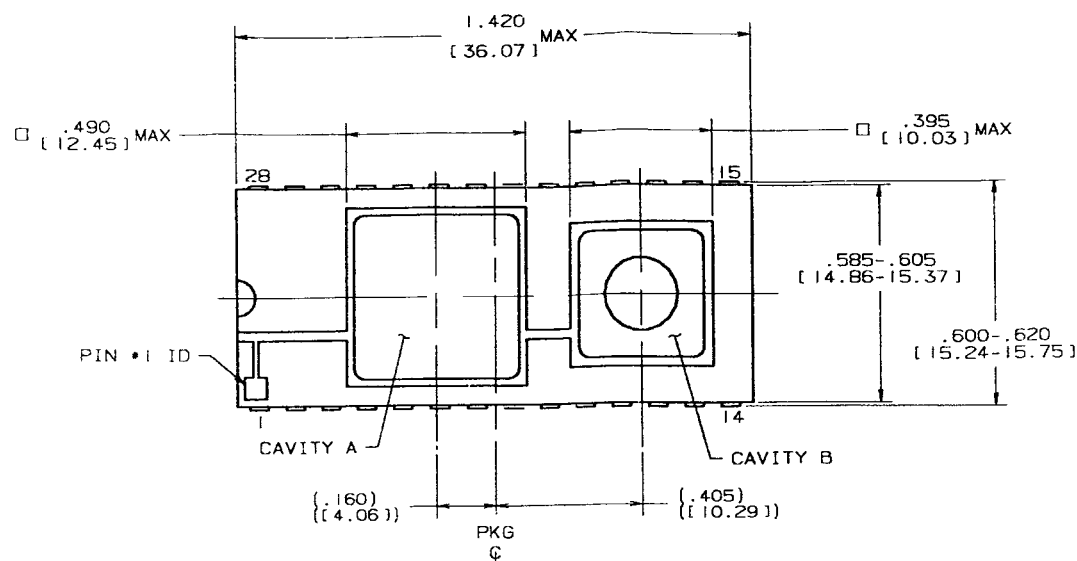
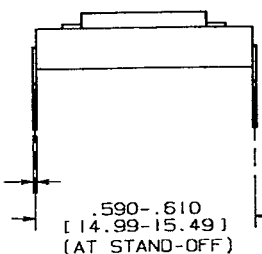


REVISIONS				
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
A	RELEASE TO DOCUMENT CONTROL	07978	06/19/90	PG/RK



.010 $\pm$.002
-.001
+0.05
[0.25-0.03] TYP



NOTES: UNLESS OTHERWISE SPECIFIED

1. LEAD FINISH IS 60 MICROINCHES/1.52 MICROMETERS GOLD MINIMUM OVER 50-350 MICROINCHES/1.27-8.89 MICROMETERS NICKEL.

CONTROLLING DIMENSION: INCH			
DATE	06/19/90	NATIONAL SEMICONDUCTOR CORPORATION 2900 Semiconductor Drive, Santa Clara, CA 95052-8090	
DRAWN	PAMELA BIFFORD	HERMETIC DIP, SIDE BRAZE, 28 LEAD, DUAL CAVITY	
DESIGN	CHK. <i>Michael Shady</i>	06/25/90	SCALE
ENGR. CHK.	<i>Roman Collier</i>	6/26/90	SIZE
APPROVAL			DRAWING NUMBER
PROJECTION		REV	
INCH (MM)		N/A C MKT-D28G A	
FORMERLY:		SHEET 1 OF 1	